

1 A Slew Rate Controlled Load Switch with Reverse Blocking

DESCRIPTION

The SiP32431 is a slew rate controlled high side switch with reverse blocking capability. The switch is of a low ON resistance p-channel MOSFET that supports continuous current up to 1 A.

The SiP32431 operates with an input voltage from 1.5 V to 5.5 V.

The SiP32431 features low input logic level to interface with low control voltage from microprocessors. This device has a very low operating current, typically 50 pA.

The SiP32431 is available in lead (Pb)-free package options including 6 pin SC70-6, and 4 pin TDFN4 1.2 mm x 1.6 mm DFN4 packages. The operation temperature range is specified from -40 $^{\circ}$ C to +85 $^{\circ}$ C.

The SiP32431 compact package options, operation voltage range, and low operating current make it a good fit for battery power applications.

FEATURES

- 1.5 V to 5.5 V input voltage range
- Very low $R_{DS(on)}$, typically 105 m Ω at 5 V and 135 m Ω at 3 V for TDFN4 1.2 mm x 1.6 mm package
- Typical 147 m Ω at 5 V and 178 m Ω at 3 V for SC70-6 package
- Slew rate controlled turn-on time: 100 µs
- Low quiescent current < 1 μA
- Low shutdown current < 1 μ A
- Reverse blocking capability
- SC70-6 and TDFN4 1.2 mm x 1.6 mm packages
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Cellular telephones
- Digital still cameras
- Personal digital assistants (PDA)
- Hot swap supplies
- Notebook computers
- Personal communication devices
- Portable Instruments

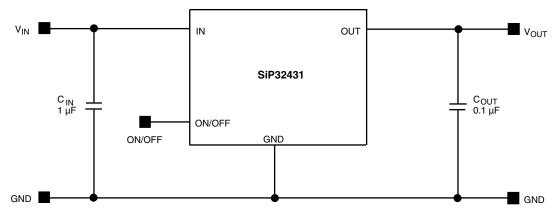


Fig. 1 - SiP32431 Typical Application Circuit

ORDERING INFORMATION					
TEMPERATURE RANGE	PACKAGE	MARKING	PART NUMBER		
-40 °C to 85 °C	SC70-6	MAxx	SiP32431DR3-T1GE3		
-40 0 10 85 0	TDFN4 1.2 mm x 1.6 mm	Dx	SiP32431DNP3-T1GE4		

Notes

- x = lot code
- -GE3 denotes halogen-free and RoHS-compliant
- Please use the SiP32431DR3-T1GE3 to replace SiP32431DR3-T1-E3

S15-1821-Rev. C, 10-Aug-15

1 For technical questions, contact: <u>powerictechsupport@vishay.com</u> Document Number: 66597

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TYPICAL APPLICATION CIRCUIT



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SiP32431

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ABSOLUTE MAXIMUM RATINGS	5			
PARAMETER	LIMIT	UNIT		
Supply Input Voltage (VIN)		-0.3 to 6		
Enable Input Voltage (V _{ON/OFF})		-0.3 to 6	V	
Output Voltage (V _{OUT})		-0.3 to V _{IN} +0.3		
Maximum Cantinuaus Switch Current (I	SC70-6 package	1.2		
Maximum Continuous Switch Current (I _{max.})	TDFN4 1.2 mm x 1.6 mm	1.4	•	
Maximum Pulsed Current (I _{DM}) V _{IN}	$V_{IN} \ge 2.5 V$	3	— A	
(pulsed at 1 ms, 10 % duty cycle)	V _{IN} < 2.5 V	1.6	7	
ESD Rating (HBM)		4000	V	
Junction Temperature (T _J)		-40 to 125	°C	
Thermal Desistance (0,) a	6 pin SC70-6 ^b	220	°C (M)	
Thermal Resistance $(\theta_{JA})^{a}$	4 pin TDFN4 1.2 mm x 1.6 mm ^c	170	°C/W	
Deriver Dissipation (\mathbf{D}_{i})	6 pin SC70- 6 ^b	250		
Power Dissipation (P _D) ^a	4 pin TDFN4 1.2 mm x 1.6 mm ^c	324	mW	

Notes

a. Device mounted with all leads and power pad soldered or welded to PC board.

b. Derate 4.5 mW/°C above $T_A = 70$ °C.

c. Derate 5.9 mW/°C above T_A = 70 °C, see PCB layout.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE			
PARAMETER	LIMIT	UNIT	
Input Voltage Range (V _{IN})	1.5 to 5.5	V	
Operating Temperature Range	-40 to 85	°C	

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SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED $V_{IN} = 5, T_A = -40 \degree C to 85 \degree C$		LIMITS -40 °C TO 85 °C			UNIT
		(Typical values are at T _A = 25 °	°C)	MIN. ^a	TYP. ^b	MAX. ^a	
Operating Voltage ^c	V _{IN}			1.5	-	5.5	V
Quiescent Current	ا _Q	On/off = active		-	0.00005	1	
Off Supply Current	I _{Q(off)}	On/off = inactive, out = oper	ı	-	-	1	μA
Off Switch Current	I _{SD(off)}	On/off = inactive, out = 0		-	-	1	μΑ
Reverse Blocking Current	I _{RB}	$V_{OUT} = 5.5 \text{ V}, V_{IN} = 0, V_{on/off} = ina$	active	-	0.13	1	
		V _{IN} = 5 V, I _I = 500 mA, T _A = 25 °C	SC70-6	-	147	230	
		$v_{\rm IN} = 5 v$, $I_{\rm L} = 500 {\rm mA}$, $I_{\rm A} = 25 {\rm G}$	TDFN4	-	105	230	
		V 40VI 500 mA T 05 °C	SC70-6	-	155	250	
	R _{DS(on)}	V_{IN} = 4.2 V, I_L = 500 mA, T_A = 25 °C	TDFN4	-	110		mΩ
On-Resistance		$V_{IN} = 3 \text{ V}, \text{ I}_{L} = 500 \text{ mA}, \text{ T}_{A} = 25 \text{ °C}$	SC70-6	-	178	290	
On-Resistance			TDFN4	-	135		
		V_{IN} = 1.8 V, I_L = 500 mA, T_A = 25 $^\circ C$ -	SC70-6	-	275	- 480 - 520	
			TDFN4	-	230		
		V _{IN} = 1.5 V, I _I = 500 mA, T _A = 25 °C	SC70-6	-	395		
		$v_{\rm IN} = 1.5 v, i_{\rm L} = 500 {\rm mA}, i_{\rm A} = 25 {\rm C}$	TDFN4	-	350		
On-Resistance TempCoefficient	TD _{RDS}			-	2800	-	ppm/°C
		$V_{IN} \ge 1.5 \text{ V to} < 1.8 \text{ V}$		-	-	0.3	
On/Off Input Low Voltage ^c	VIL	$V_{IN} \ge 1.8 \text{ V to} < 2.7 \text{ V}$		-	-	0.4	
		$V_{IN} \ge 2.7 \text{ V to} \le 5.5 \text{ V}$		-	-	0.6	v
		$V_{IN} \ge 1.5 \text{ V to} < 2.7 \text{ V}$		1.3	-	- \	v
On/Off Input Low Voltage c	VIH	$V_{IN} \ge 2.7 \text{ V to} < 4.2 \text{ V}$		1.5	-	-	
		$V_{IN} \ge 4.2 \text{ V to} \le 5.5 \text{ V}$		1.8	-	-	
On/Off Input Leakage	I _{SINK}	V _{On/Off} = 5.5 V		-	-	1	μA
Output Turn-On Delay Time	t _{d(on)}			-	20	40	
Output Turn-On Rise Time	t _(on)	V_{IN} = 5 V, R_{load} = 10 Ω , T_A = 25	°C	-	140	180	μs
Output Turn-Off Delay Time	t _{d(off)}			-	4	10]

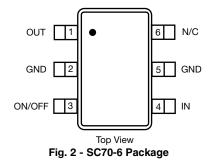
Notes

a. The algebriac convention whereby the most negative value is a minimum and the most positive a maximum.

b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing

c. For V_{IN} outside this range consult typical on/off threshold curve.

PIN CONFIGURATION



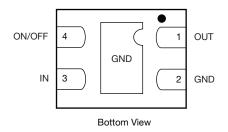


Fig. 3 - TDFN4 1.2 mm x 1.6 mm Package

CRIPTION	l	
MBER	NAME	FUNCTION
TDFN4	NAME	
3	IN	This pin is the p-channel MOSFET source connection. Bypass to ground through a 1 μ F capacitor
2	GND	Ground connection
4	ON/OFF	Enable input
1	OUT	This pin is the p-channel MOSFET drain connection. Bypass to ground through a 0.1 μ F capacitor
	/BER	TDFN4NAME3IN2GND4ON/OFF

S15-1821-Rev. C, 10-Aug-15

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TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

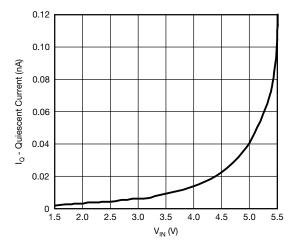


Fig. 4 - Quiescent Current vs. Input Voltage

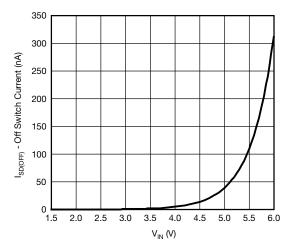


Fig. 5 - Off Switch Current vs. Input Voltage

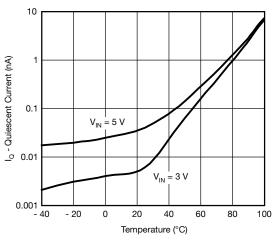


Fig. 6 - Quiescent Current vs. Temperature

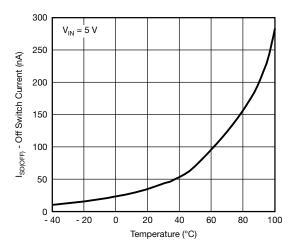


Fig. 7 - Off Switch Current vs. Temperature

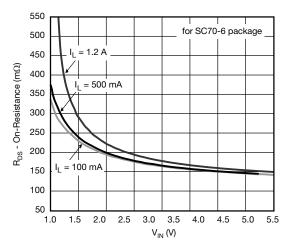


Fig. 8 - R_{DS(on)} vs. V_{IN} for SC70-6 Package

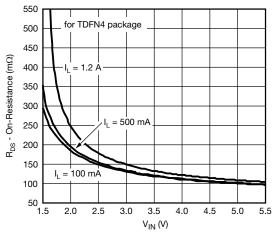


Fig. 9 - R_{DS(on)} vs. Input Voltage

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TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

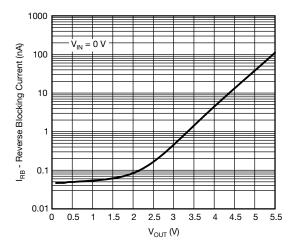


Fig. 10 - Reverse Blocking Current vs. VOUT

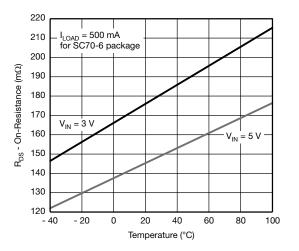


Fig. 11 - R_{DS(on)} vs. Temperature

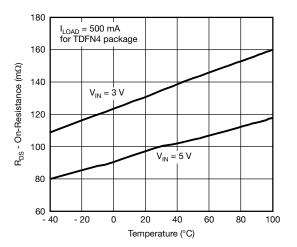


Fig. 12 - R_{DS(on)} vs. Temperature

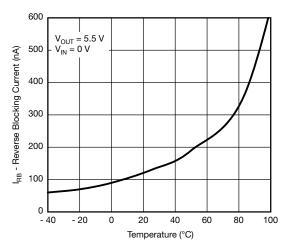


Fig. 13 - Reverse Blocking Current vs. Temperature

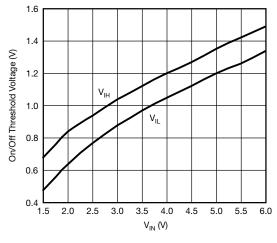


Fig. 14 - On/Off Threshold vs. Input Voltage



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TYPICAL WAVEFORMS

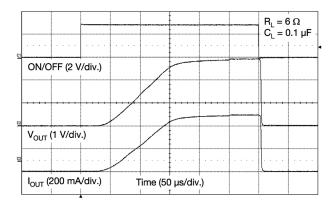


Fig. 15 - Switching (V_{IN} = 3 V)

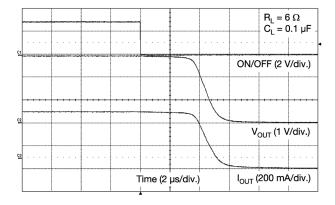
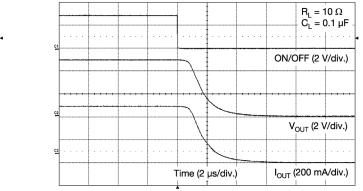


Fig. 17 - Turn-Off (V_{IN} = 3 V)

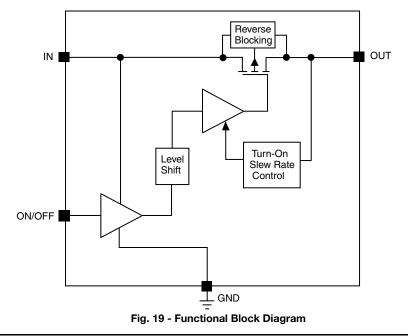




$\begin{array}{c} \mathsf{P}_{L} = 10 \ \Omega \\ \mathsf{C}_{L} = 0.1 \ \mu \mathsf{F} \\ \mathsf{C}_{L} = 0.1 \ \mathsf{C}_{L} = 0.1 \ \mathsf{C}_{L} \\ \mathsf{C}_{L} = 0.1 \ \mathsf{C}_{L} = 0.1 \ \mathsf{C}_{L} \\ \mathsf{C}_{L} = 0.1 \ \mathsf{C}_{L} \\ \mathsf{C}_{L} =$

Fig. 16 - Switching (V_{IN} = 5 V)

BLOCK DIAGRAM



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PCB LAYOUT

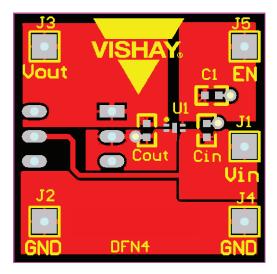


Fig. 20 - Top, TDFN4 1.2 mm x 1.6 mm PCB Layout

DETAILED DESCRIPTION

The SiP32431 is a p-channel MOSFET power switches designed for high-side slew rate controlled load-switching applications. Once turned on, the slew-rate control circuitry is activated and current is ramped in a linear fashion until it reaches the level required for the output load condition. This is accomplished by first elevating the gate voltage of the MOSFET up to its threshold voltage and then by linearly increasing the gate voltage until the MOSFET becomes fully enhanced. At this point, the gate voltage is then quickly increased to the full input voltage to reduce $R_{DS(on)}$ of the MOSFET switch and minimize any associated power losses.

APPLICATION INFORMATION

Input Capacitor

While a bypass capacitor on the input is not required, a 1 μF or larger capacitor for $C_{\rm IN}$ is recommended in almost all applications. The bypass capacitor should be placed as physically close as possible to the SiP32431 to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries in portable devices.

Output Capacitor

A 0.1 μ F capacitor or larger across V_{OUT} and GND is recommended to insure proper slew operation. C_{OUT} may be increased without limit to accommodate any load transient condition with only minimal affect on the SiP32431 turn on slew rate time. There are no ESR or capacitor type requirement.

Enable

The on/off pin is compatible with both TTL and CMOS logic voltage levels.

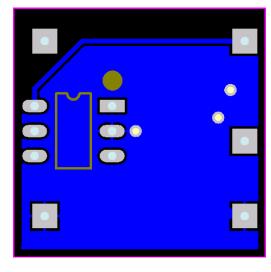


Fig. 21 - Bottom, TDFN4 1.2 mm x 1.6 mm PCB Layout

Protection Against Reverse Voltage Condition

The SiP32431 contains a body snatcher that normally connect the body to the source (IN) when the device is enable. In case where the device is disabled but the V_{OUT} is higher than the V_{IN} , the n-type body is switched to OUT, reverse bias the body diode to prevent the current from going back to the input.

Thermal Considerations

The SiP32431 is designed to maintain a constant output load current. Due to physical limitations of the layout and assembly of the device the maximum switch current is 1 A, as stated in the Absolute Maximum Ratings table. However, another limiting characteristic for the safe operating load current is the thermal power dissipation of the package. To obtain the highest power dissipation (and a thermal resistance of 170 °C/W) the power pad of the device should be connected to a heat sink on the printed circuit board.

The maximum power dissipation in any application is dependent on the maximum junction temperature, $T_{J (max.)} = 125 \text{ °C}$, the junction-to-ambient thermal resistance for the TDFN4 1.2 mm x 1.6 mm package, $\theta_{J-A} = 170 \text{ °C/W}$, and the ambient temperature, T_A , which may be formulaically expressed as:

P (max.) =
$$\frac{T_{J (max.)} - T_{A}}{\theta_{J-A}} = \frac{125 - T_{A}}{170}$$

It then follows that, assuming an ambient temperature of 70 °C, the maximum power dissipation will be limited to about 324 mW.

So long as the load current is below the 1 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the $R_{DS(on)}$ at the ambient temperature.

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As an example let us calculate the worst case maximum load current at $T_A = 70$ °C. The worst case $R_{DS(on)}$ at 25 °C occurs at an input voltage of 1.5 V and is equal to 520 m Ω . The $R_{DS(on)}$ at 70 °C can be extrapolated from this data using the following formula

 $R_{DS(on)}$ (at 70 °C) = $R_{DS(on)}$ (at 25 °C) x (1 + $T_C x \Delta T$)

Where T_C is 3300 ppm/°C. Continuing with the calculation we have

R_{DS(on)} (at 70 °C) = 520 mΩ x (1 + 0.0033 x (70 °C - 25 °C)) = 597 mΩ

The maximum current limit is then determined by

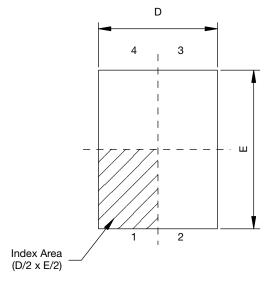
$$I_{LOAD (max.)} < \sqrt{\frac{P (max.)}{R_{DS(on)}}}$$

which in case is 0.74 A. Under the stated input voltage condition, if the 0.74 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

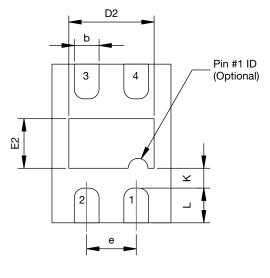
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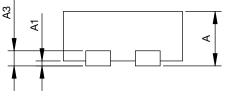
TDFN4 1.2 x 1.6 Case Outline



Top View



Bottom View



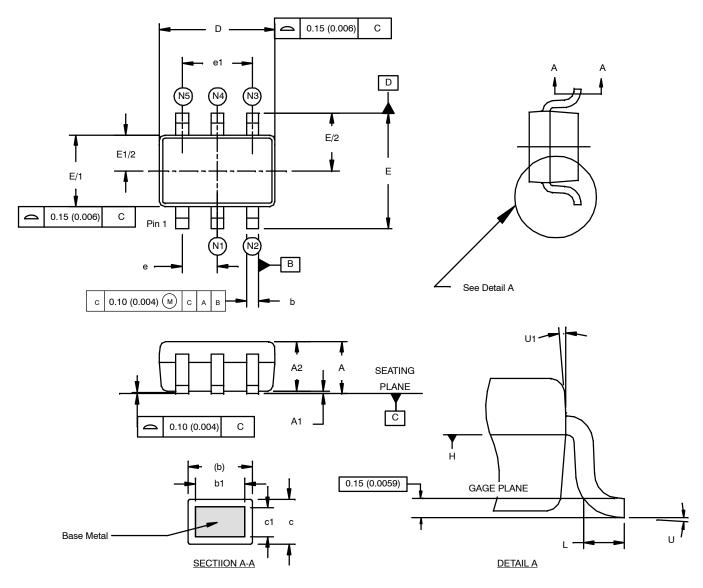
Side View

		MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
А	0.50	0.55	0.60	0.020	0.022	0.024		
A1	0.00	-	0.05	0.00	-	0.002		
A3		0.15 REF.			0.006			
b	0.20	0.25	0.30	0.008	0.010	0.012		
D	1.15	1.20	1.25	0.045	0.047	0.049		
D2	0.81	0.86	0.91	0.032	0.034	0.036		
е		0.50 BSC			0.020			
E	1.55	1.60	1.65	0.061	0.063	0.065		
E2	0.45	0.50	0.55	0.018	0.020	0.022		
K		0.25 TYP.			0.010 TYP.	•		
L	0.25	0.30	0.35	0.010	0.012	0.014		

Revision: 07-Nov-11



SC-70: 3/4/5/6-LEADS (PIC ONLY)



Pin	LEAD CO	OUN	Г	
Code	3	4	5	6
N1	-	-	2	2
N2	2	2	3	3
N3	-	3	4	4
N4	3	-	-	5
N5	-	4	5	6

NOTES:

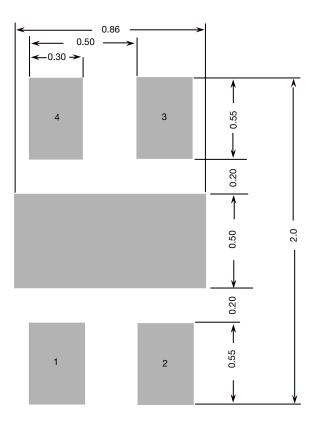
- 1. Dimensioning and tolerancing per ANSI Y14.5M-1994.
- 2. Controlling dimensions: millimeters converted to inch dimensions are not necessarily exact.
- Dimension "D" does not include mold flash, protrusion or gate burr. Mold flash, protrusion or gate burr shall not exceed 0.15 mm (0.006 inch) per side.
- 4. The package top shall be smaller than the package bottom. Dimension "D" and "E1" are determined at the outer most extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interlead flash, but including any mismatch between the top and bottom of the plastic body.



	Μ	ILLIMETE	INCHES					
Dim	Min	Nom	Max	Min	Nom	Max		
Α	0.80	-	1.10	0.031	-	0.043		
A1	0.00	-	0.10	0.000	-	0.004		
A2	0.80	0.90	1.00	0.031	0.035	0.040		
b	0.15	-	0.30	0.006	-	0.012		
b1	0.15	0.20	0.25	0.006	0.008	0.010		
С	0.08	-	0.25	0.003	-	0.010		
c1	0.08	0.13	0.20	0.003	0.005	0.008		
D	1.90	2.10	2.15	0.074	0.082	0.084		
Е	2.00	2.10	2.20	0.078	0.082	0.086		
E ₁	1.15	1.25	1.35	0.045	0.050	0.055		
е		0.65 BSC		0.0255 BSC				
e ₁		1.30 BSC			0.0512 BSC			
L	0.26	0.36	0.46	0.010	0.014	0.018		
U	0°	-	8°	0°	-	8 °		
U1	4°		10°	4°		10°		



RECOMMENDED MINIMUM PADS FOR TDFN4 1.2 x 1.6



Recommended Minimum Pads Dimensions in mm



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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

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